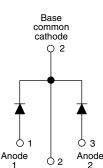
VS-HFA50PA60CHN3

Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 2 x 25 A



www.vishay.com



Common cathode

PRODUCT SUMMARY							
Package	TO-247AC						
I _{F(AV)}	2 x 25 A						
V _R	600 V						
V _F at I _F	1.3 V						
t _{rr} typ.	23 ns						
T _J max.	150 °C						
Diode variation	Single die						

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Material categorization:
- for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



RoHS COMPLIANT HALOGEN FREE

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA50PA60CHN3 is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A per leg continuous current, the VS-HFA50PA60CHN3 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED[®] product line features extremely low values of peak recovery current (IRRM) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA50PA60CHN3 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Cathode to anode voltage	V _R		600	V					
Maximum continuous forward current per leg	I_	T _C = 100 °C	25						
per device	IF	1C = 100 C	50	А					
Single pulse forward current	I _{FSM}		225	A					
Maximum repetitive forward current	I _{FRM}		100						
Maximum power dissipation	р	T _C = 25 °C	150	W					
	P _D	T _C = 100 °C	60	VV					
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C					

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VS-HFA50PA60CHN3

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ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-			
Maximum forward voltage		I _F = 25 A		-	1.3	1.7	v		
	V _{FM}	I _F = 50 A	See fig. 1	-	1.5	2.0			
		I _F = 25 A, T _J = 125 °C		-	1.3	1.7			
Maximum reverse	1	$V_R = V_R$ rated	Coofig 0	-	1.5	20			
leakage current	IRM	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	See fig. 2	-	600	2000	μA		
Junction capacitance	CT	V _R = 200 V See fig. 3		-	55	100	pF		
Series inductance	L _S	Measured lead to lead 5 mm from p	ackage body	-	12	-	nH		

DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	A/μs, V _R = 30 V	-	23	-			
Reverse recovery time See fig. 5, 10	t _{rr1}	T _J = 25 °C		-	50	-	ns		
	t _{rr2}	T _J = 125 °C	I _F = 25 A dI _F /dt = 200 A/μs V _R = 200 V	-	105	-			
Peak recovery current See fig. 6	I _{RRM1}	T _J = 25 °C		-	4.5	-	A		
	I _{RRM2}	T _J = 125 °C		-	8.0	-			
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	112	-	nC		
See fig. 7	Q _{rr2}	T _J = 125 °C		-	420	-	nc		
Peak rate of fall of recovery	dl _{(rec)M} /dt1	T _J = 25 °C		-	250	-	A∕µs		
current during t _b See fig. 8	dl _{(rec)M} /dt2	T _J = 125 °C		-	160	-	-ν μο		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C			
Junction to case, single leg conducting	P		-	-	0.83				
Junction to case, both legs conducting	— R _{thJC}		-	-	0.42				
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	K/W			
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-				
Maight			-	6.0	-	g			
Weight			-	0.21	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style TO-247AC		HFA50	PA60CH				

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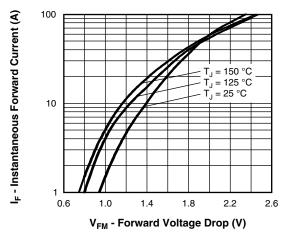
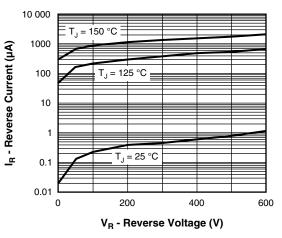
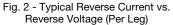


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)





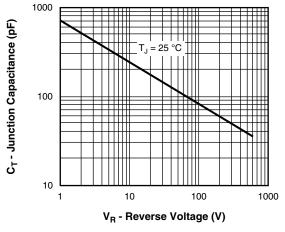
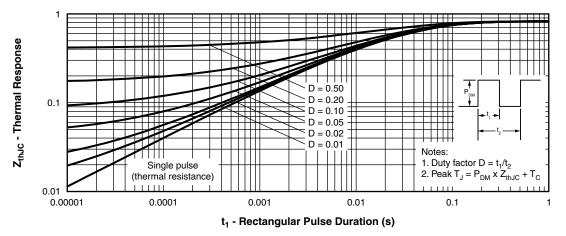


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





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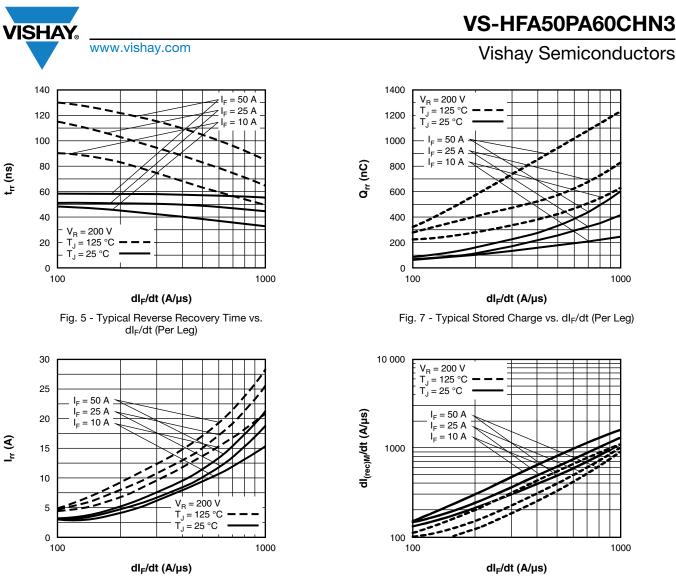


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)



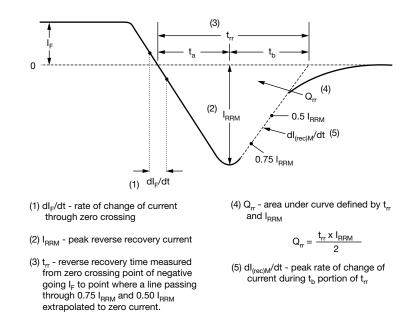


Fig. 9 - Reverse Recovery Waveform and Definitions

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evice code	VS-	HF	A	50	PA	60	С	н	N3
	1	2	3	4	5	6	7	8	9
	 Vishay Semiconductors product HEXFRED[®] family Electron irradiated Current rating (50 = 50 A) PA = TO-247AC Voltage rating: (60 = 600 V) Circuit configuration 								
	8 - 9 -	C = H = Env	commo AEC-Q ironmer	on catho 101 qua ntal digit en-free,	de lified :	complia	nt, and f	totally le	ad (Pb)

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-HFA50PA60CHN3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95223					
Part marking information	TO-247AC-N3	www.vishay.com/doc?95007					

VISHAY www.vishay.com **ORDERING INFORMATION TABLE** Dev

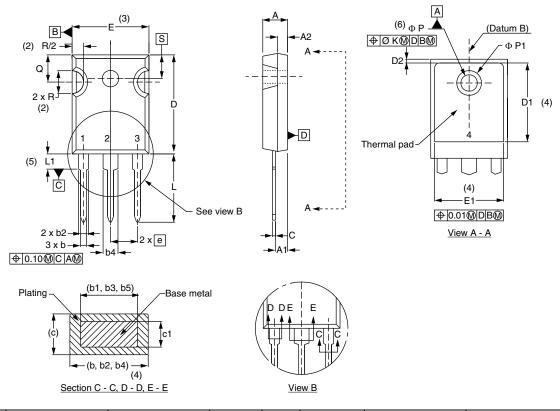
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TO-247AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES		OTES SYMBOL		MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.46	-	0.530	-	
b	0.99	1.40	0.039	0.055			e	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0	010	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØР	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	6.98	-	0.275	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	S 5.51 BSC 0.217 BSC		' BSC		
D1	13.08	-	0.515	-	4							

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

 $^{(7)}\,$ Outline conforms to JEDEC $^{\tiny (\! R)}$ outline TO-247 with exception of dimension c

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